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Date:	June 8, 2007		
To:	Mail Stop Amendment	Fax Telephone #:	571-273-8300
	Group Art Unit 2812	Office Telephone #:	571-272-1000
	United States Patent and Trademark Office		
From:	Hugh H. Matsubayashi	Date Sent:	June 8, 2007
Subject:	U.S. Application Serial No. 11/125,445	Fax Operator:	S Badon
Our Ref. No.:	AB-1432 US		

This transmittal consists of 7 total page(s), including this cover sheet.

<p align="center">CERTIFICATE OF TRANSMISSION I hereby certify that this Fac(s) Transmittal is being facsimile transmitted to the USPTO (571) 273-8300, on June 8, 2007 By: <u>Sheila Badon</u> Sheila Badon</p>

Re: U.S. Application Serial No. 10/532,459
Date Filed: November 2, 2005
Attorney Docket No. AB-1432 US

Enclosed:

- Certificate of Facsimile Transmission (1 pg);
- Preliminary Amendment (5 pgs).

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:	KIM, Hyun-Jae and KANG, Myung-Koo	RECEIVED CENTRAL FAX CENTER
Assignee:	SAMSUNG ELECTRONICS CO., LTD.	JUN 08 2007
Title:	METHOD OF POLYCRYSTALLIZATION, METHOD OF MANUFACTURING POLYSILICON THIN FILM TRANSISTOR, AND LASER IRRADIATION DEVICE THEREFOR (As Amended)	
Application No.:	10/532,459	Filing Date: 11/02/2005
Examiner:	BOOTH, Richard A.	Group Art Unit: 2812
Docket No.:	AB-1432 US	Confirmation No.: 1783

San Jose, California
June 8, 2007

Via Facsimile to (571) 273-8300

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Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

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Dear Sir:

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Preliminary Amendment (5 pages)

Dated: June 8, 2007


David W. Heid, Reg. No. 25,875

Number of pages (including this sheet): 6

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PRELIMINARY AMENDMENT

Dear Sir:

Prior to examination on the merits, please amend the application as set forth below.

Amendment to the Specification begin on page 2.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks begin on page 5.

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